

DATA SHEET



MOS FIELD EFFECT TRANSISTOR

2SK4145

SWITCHING

N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4145 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low on-state resistance
 $R_{DS(on)} = 10 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 42 \text{ A)}$
- Low input capacitance
 $C_{iss} = 5300 \text{ pF TYP.}$

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4145-S19-AY ^{Note}	Pure Sn (Tin)	Tube 50 p/tube	TO-220 typ. 1.9 g

Note Pb-free (This product does not contain Pb in the external electrode).

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	60	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) (T _C = 25°C)	I _{D(DC)}	±84	A
Drain Current (pulse) ^{Note1}	I _{D(pulse)}	±215	A
Total Power Dissipation (T _C = 25°C)	P _{T1}	84	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.5	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current ^{Note2}	I _{AS}	32	A
Single Avalanche Energy ^{Note2}	E _{AS}	102	mJ

Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω, V_{GS} = 20 → 0 V, L = 100 μH

THERMAL RESISTANCE

Channel to Case Thermal Resistance	R _{th(ch-C)}	1.49	°C/W
Channel to Ambient Thermal Resistance	R _{th(ch-A)}	83.3	°C/W

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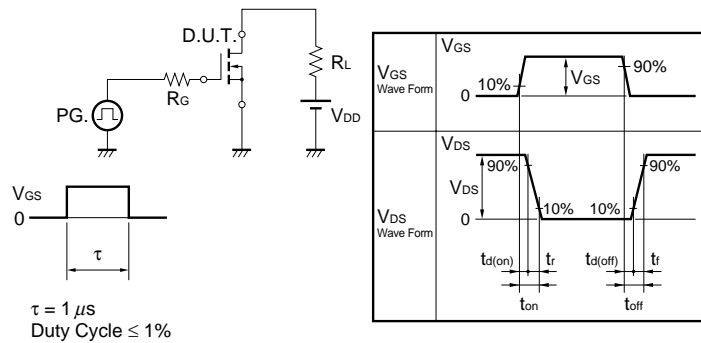
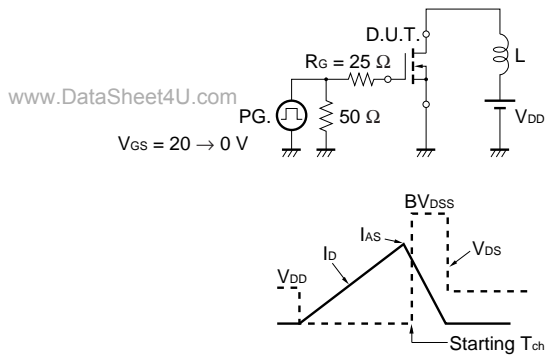
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.0	3.0	4.0	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 10 V, I _D = 30 A	16	31		S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)}	V _{GS} = 10 V, I _D = 42 A		7	10	mΩ
Input Capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		5300		pF
Output Capacitance	C _{oss}			540		pF
Reverse Transfer Capacitance	C _{rss}			330		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 30 V, I _D = 42 A,		25		ns
Rise Time	t _r	V _{GS} = 10 V,		17		ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		66		ns
Fall Time	t _f			9		ns
Total Gate Charge	Q _G	V _{DD} = 48 V,		90		nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V,		21		nC
Gate to Drain Charge	Q _{GD}	I _D = 84 A		30		nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 84 A, V _{GS} = 0 V		1.0	1.5	V
Reverse Recovery Time	t _{rr}	I _F = 84 A, V _{GS} = 0 V,		43		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		62		nC

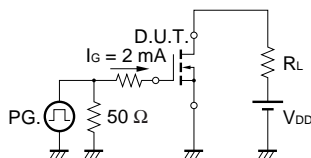
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

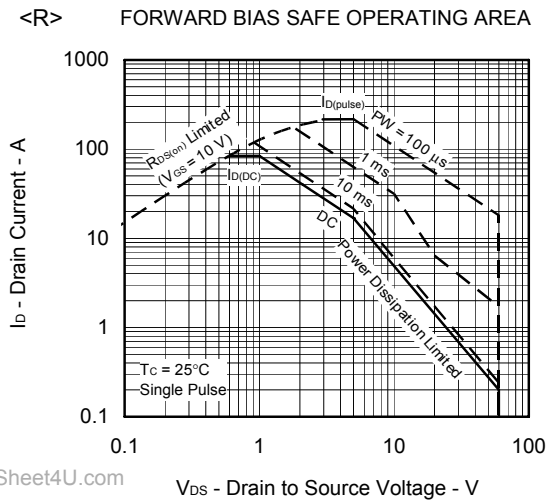
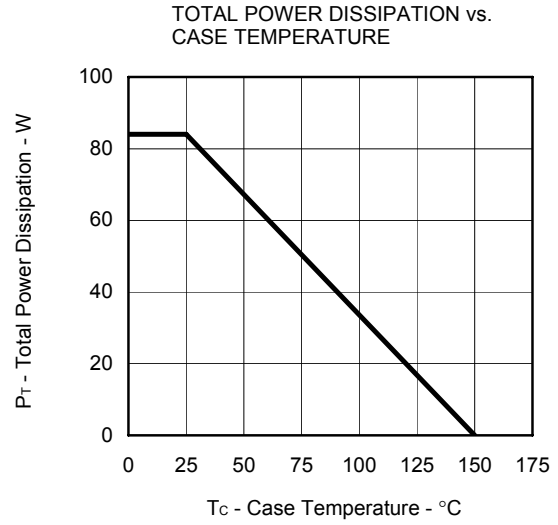
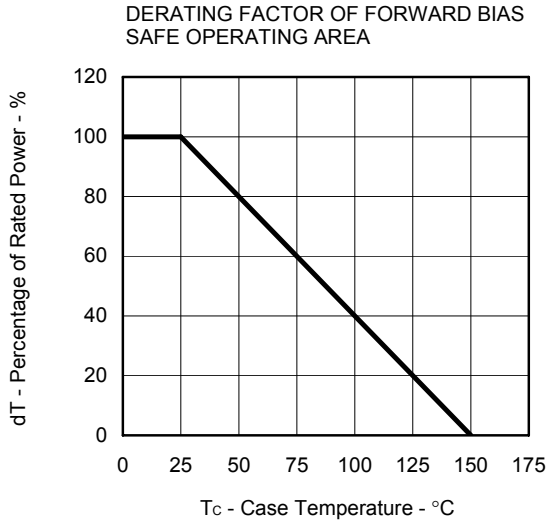
TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE



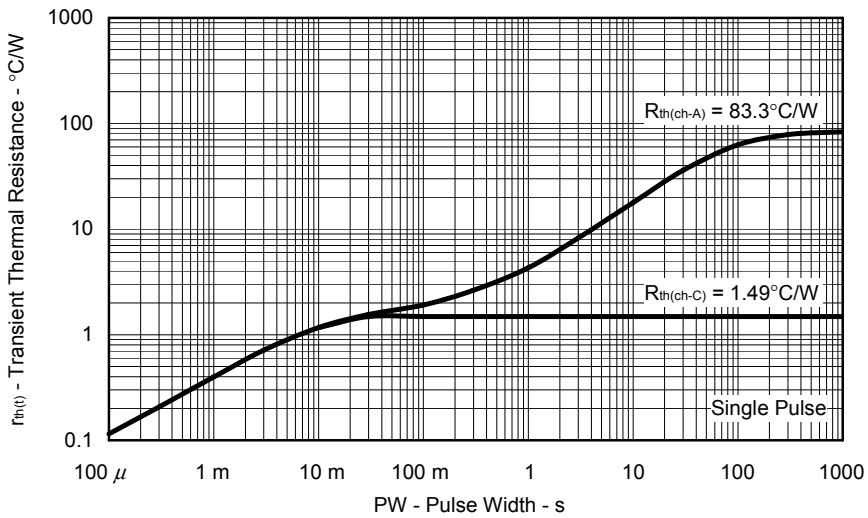
TYPICAL CHARACTERISTICS (T_A = 25°C)



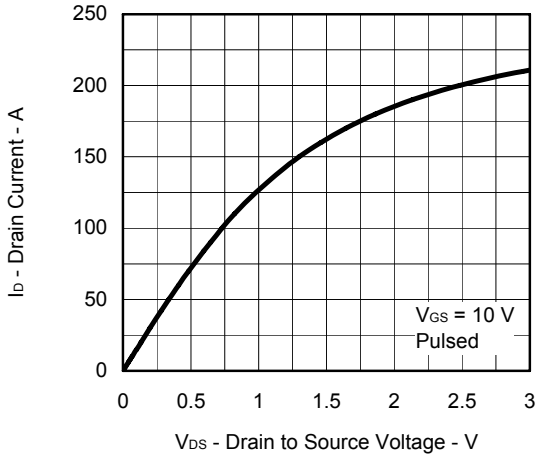
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V_{DS} - Drain to Source Voltage - V

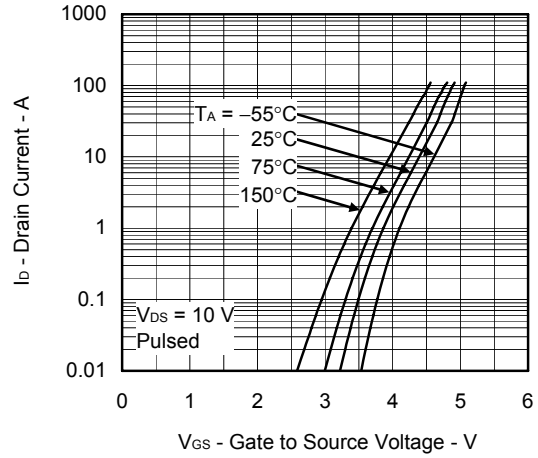
<R> TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



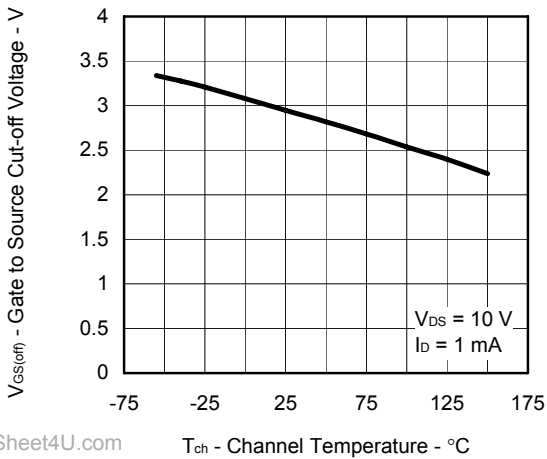
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



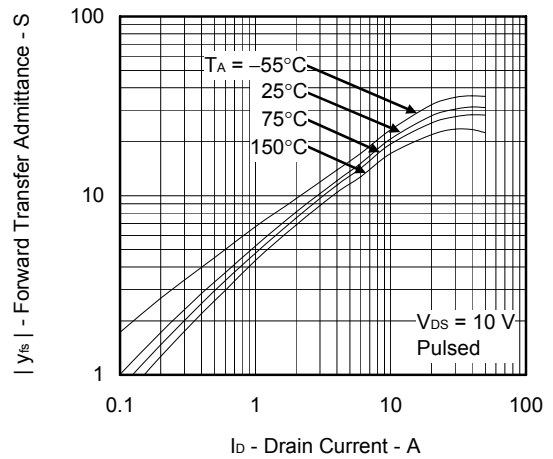
FORWARD TRANSFER CHARACTERISTICS



GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

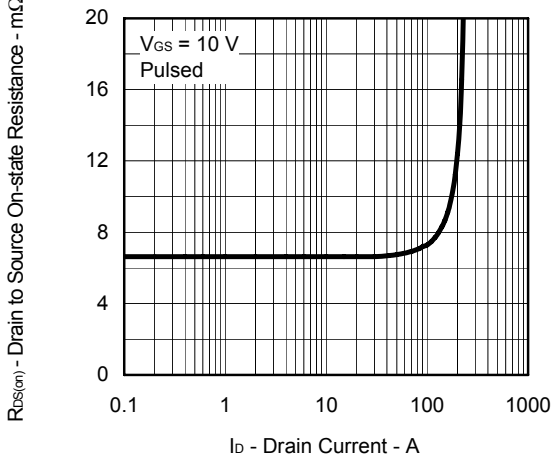


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

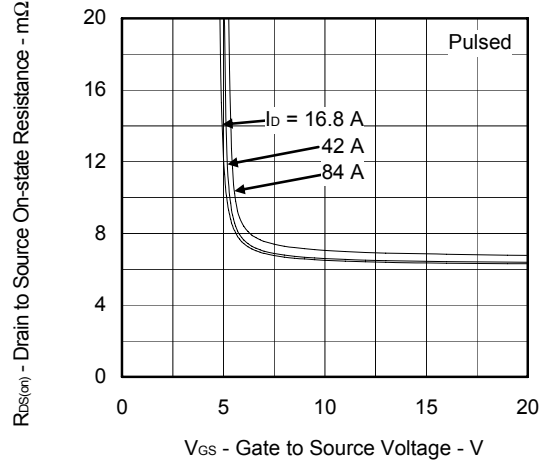


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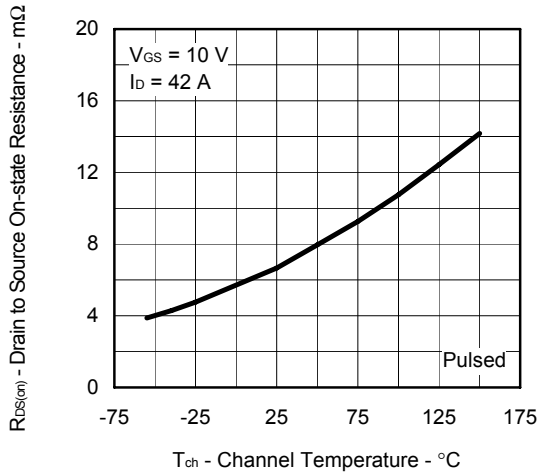
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



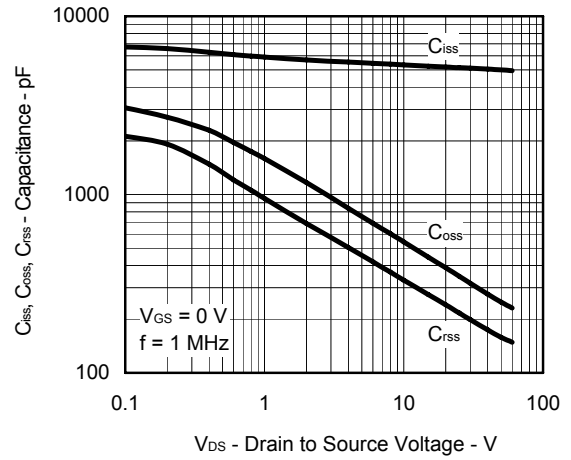
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



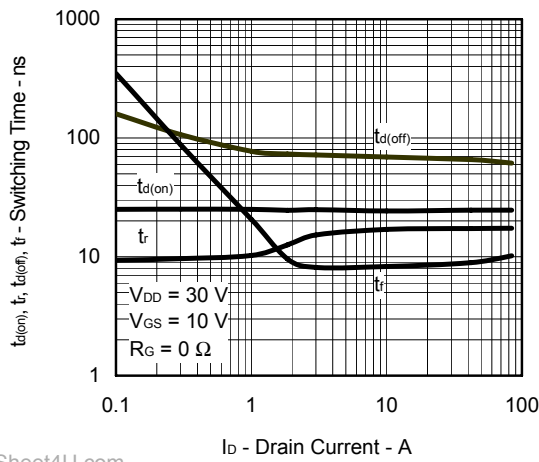
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



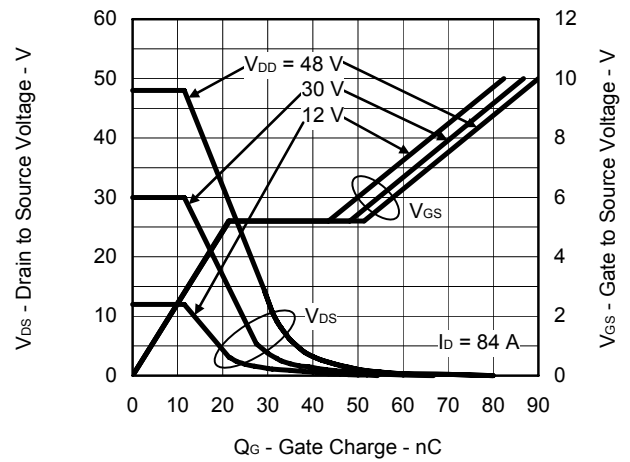
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS

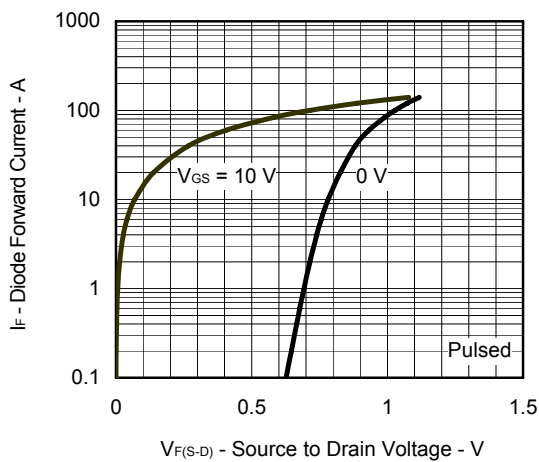


DYNAMIC INPUT/OUTPUT CHARACTERISTICS

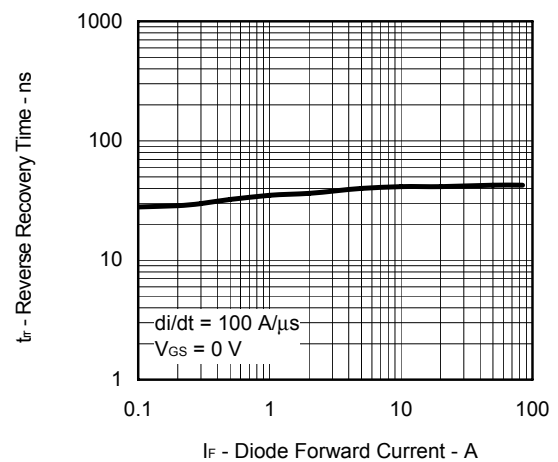


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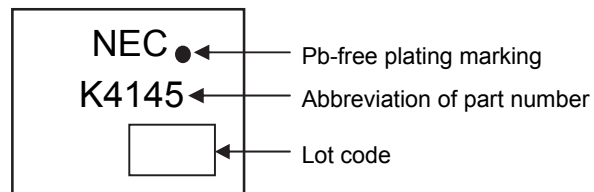
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The 2SK4145 should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Wave soldering	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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